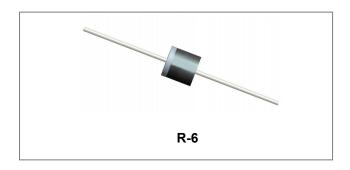






15SQ SERIES SCHOTTKY BARRIER RECTIFIER



Features

- Super-high speed & low noise switching
- Low voltage drop
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- DC-DC converters
- AC adapter
- High frequency rectification circuit
- Bypass diodes

Maximum Ratings:

Characteristics	Symbol	Conditions	Valu	16	Units
		-	15SQ030	30	
Peak Repetitive Reverse Voltage	V _{RRM} V _{RWM} V _R		15SQ045	45	
Working Peak Reverse Voltage			15SQ050	50	
DC Blocking Voltage			15SQ060	60	7
			15SQ100	100	1
Average Rectified Forward Current	I _{F(AV)}	R- load, Ta=50℃	15		А
Surge(Non-repetitive) Forward Current IFSN			15SQ030		
		9 2ms single helf sine	no single helf sine 15SQ045	300	
	I _{FSM}	8.3ms single half sine-	15SQ050	300	V
		wave	15SQ060		
			15SQ100	340	

Electrical Characteristics:

Characteristics	Symbol	Conditions			Тур.	Max.	Units
Peak Forward Voltage*				15SQ030	0.52	0.55	
				15SQ045	0.52	0.55	
	VFM	I _{FM} =15.0A,Та	a=25℃	15SQ050	0.58	0.68	V
				15SQ060	0.58	0.68	
				15SQ100	0.78	0.83	
Peak Reverse Current*	IRRM1	V _{RM} =V _{RRM}	Ta=25℃	-	0.05	0.5	m A
	IRRM2	T VRM-VRRM	Ta=100℃	-	-	25	mA
Thermal Resistance	R θJ-c	Between junction and case		-	3.0	-	°C/W
	R øJ-L	Between jun	ction and lead	-	2.0	-] C/VV

Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature at reduced reverse voltage at reduced reverse voltage in DC forward mode	TJ	V _R ≤80%V _{RRM} V _R ≤50%V _{RRM}	-55 to +150 -55 to +180 -55 to +200	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Approximate Weight	wt	-	2.24	g

Ratings and Characteristics Curves

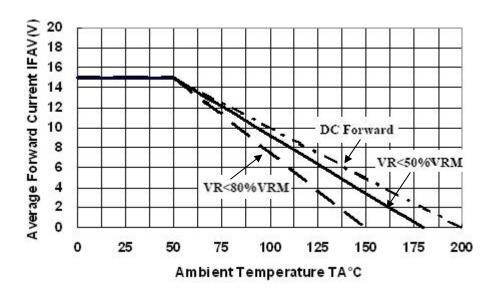
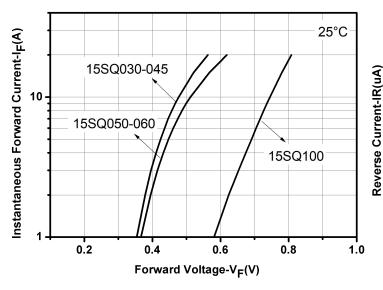


Fig.1 Current Derating









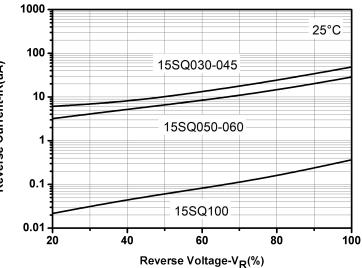
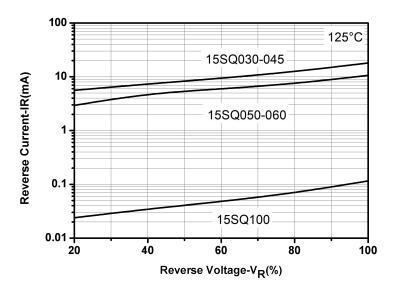


Fig.2 Typical Forward Characteristics

Fig.3 Typical Reverse Characteristics





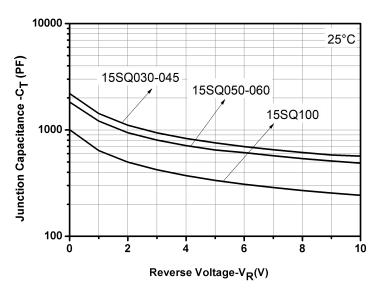


Fig.5 Typical Junction Capacitance

[•] China - Germany - Korea - Singapore - United States •

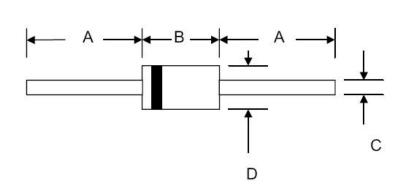
[•] http://www.smc-diodes.com - sales@ smc-diodes.com •







Mechanical Dimensions R-6



SYMBOL	Millin	neters	Inches		
STMBOL	Min.	Max.	Min.	Max.	
Α	25.4	-	1.000	-	
В	8.60	9.10	0.340	0.360	
С	1.2	1.3	0.048	0.052	
D	8.60	9.10	0.340	0.360	

Ordering Information

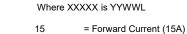
Device Package		Shipping	
15SQ030			
15SQ045	R-6		
15SQ050	R-o (Pb-Free)	500pcs / reel	
15SQ060			
15SQ100			

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

15SQ030 SSG XXXXX

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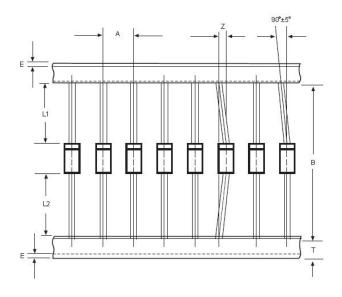


S = Package Type 030 SSG = SSG

= Device Type = Reverse Voltage (30V)

= Year WW = Week = Lot Number

Carrier Tape Specification R-6



SYMBOL	Millimeters			
STWIBOL	Min.	Max.		
А	9.50	10.50		
В	50.9	53.9		
Z	-	1.20		
Т	5.60	6.40		
E	-	0.80		
IL1-L2I	-	1.0		

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15SQ SERIES



Technical Data Data Sheet N0129, Rev. C





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